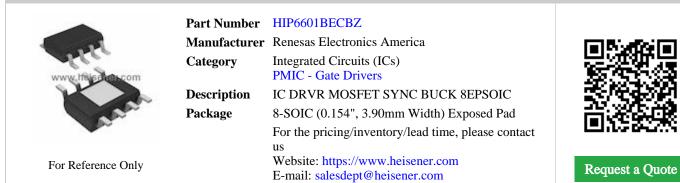


HIP6601BECBZ

HIP6601BECBZ Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



HIP6601BECBZ Specifications

Manufacturer Part Number	HIP6601BECBZ
Manufacturer	Renesas Electronics America
Category	Integrated Circuits (ICs)
	PMIC - Gate Drivers
Package	8-SOIC (0.154", 3.90mm Width) Exposed Pad
Series	-
Driven Configuration	Half-Bridge
Channel Type	Synchronous
Number of Drivers	2
Gate Type	N-Channel MOSFET
Voltage - Supply	10.8 V ~ 13.2 V
Logic Voltage - VIL, VIH	-
Current - Peak Output (Source, Sink)	_
Input Type	Non-Inverting
High Side Voltage - Max (Bootstrap)	15V
Rise / Fall Time (Typ)	20ns, 20ns
Operating Temperature	0°C ~ 125°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width) Exposed Pad
Supplier Device Package	8-SOIC-EP
	Report errors

HIP6601BECBZ Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

HIP6601BECBZ Payment Methods





If you have any question about HIP6601BECBZ, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com